





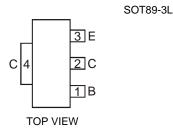
Features

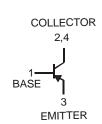
- **Epitaxial Planar Die Construction**
- Complementary NPN Type Available (DXT2222A)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free by Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.072 grams







Schematic and Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	-60	V
Collector-Base Voltage	V_{CBO}	-60	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	Ic	-600	mA
Peak Collector Current	I _{CM}	-800	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T _A = 25°C	P_{D}	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ T _A = 25°C	$R_{ hetaJA}$	125	°C/W
Operating and Storage Temperature Range	$T_{j,} T_{STG}$	-55 to +150	°C

Notes:

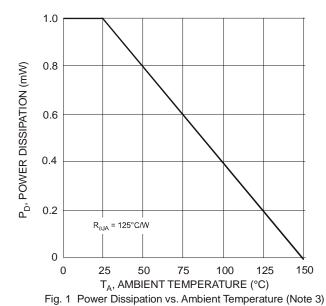
- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Device mounted on FR-4 PCB, pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf



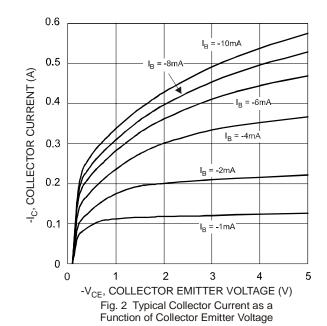
Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-60	_	V	$I_C = -10\mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-60	_	V	$I_C = -10 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5.0	_	V	$I_E = -10\mu A, I_C = 0$	
Collector Cutoff Current	I _{CBO}	_	-10	nA μA	V _{CB} = -50V, I _E = 0 V _{CB} = -50V, I _E = 0, T _A = 150°C	
Collector Cutoff Current	I _{CEX}	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$	
Emitter Cutoff Current	I _{EBO}	_	-50	nA	$V_{EB} = -5V, I_{C} = 0$	
Base Cutoff Current	I_{BL}	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -0.5V$	
ON CHARACTERISTICS (Note 4)						
DC Current Gain	h _{FE}	75 100 100 100 50	300	_	$I_{C} = -100\mu A, V_{CE} = -10V$ $I_{C} = -1.0mA, V_{CE} = -10V$ $I_{C} = -10mA, V_{CE} = -10V$ $I_{C} = -150mA, V_{CE} = -10V$ $I_{C} = -500mA, V_{CE} = -10V$	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.4 -1.6	V	I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA	
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	-1.3 -2.6	V	$I_C = -150 \text{mA}, I_B = -15 \text{mA}$ $I_C = -500 \text{mA}, I_B = -50 \text{mA}$	
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C_{obo}	_	8.0	pF	$V_{CB} = -10V$, $f = 1.0MHz$, $I_E = 0$	
Input Capacitance	C _{ibo}	_	30	pF	$V_{EB} = -2.0V$, $f = 1.0MHz$, $I_C = 0$	
Current Gain-Bandwidth Product	f⊤	200	_	MHz	$V_{CE} = -20V, I_{C} = -50mA,$ f = 100MHz	
SWITCHING CHARACTERISTICS						
Turn-On Time	t _{on}		45	ns	$V_{CC} = -30V, I_{C} = -150mA,$ $I_{B1} = -15mA$	
Delay Time	t _d	_	10	ns		
Rise Time	t _r		40	ns	IRI - IOIIIV	
Turn-Off Time	t _{off}	_	100	ns	$V_{CC} = -6.0V, I_C = -150mA,$ $I_{B1} = I_{B2} = -15mA$	
Storage Time	ts	_	80	ns		
Fall Time	t _f		30	ns		

Notes: 4. Short duration pulse test used to minimize self-heating effect.



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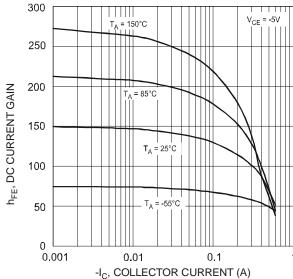


Fig. 3 Typical DC Current Gain vs. Collector Current

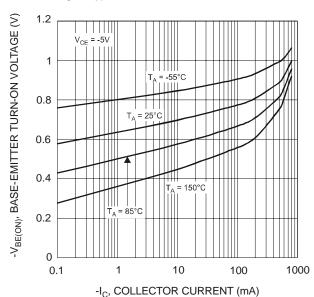


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

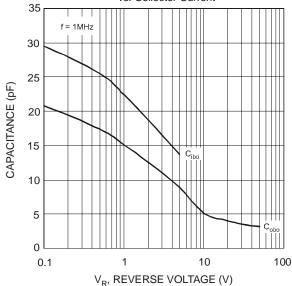


Fig. 7 Typical Capacitance Characteristics

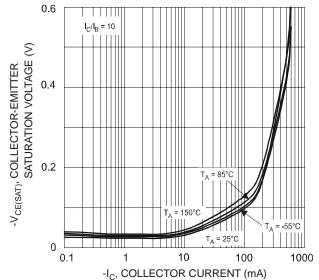


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

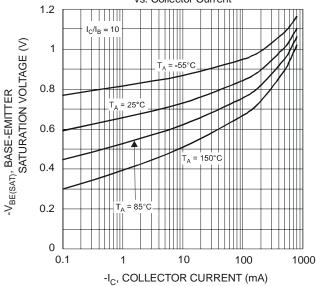


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

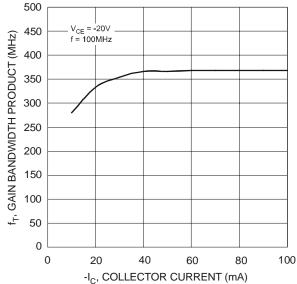


Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

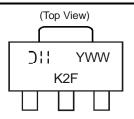


Ordering Information (Note 5)

Device	Packaging	Shipping
DXT2907A-13	SOT89-3L	2500/Tape & Reel

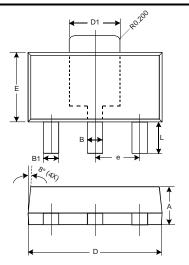
5. For packaging details go to our website at http://www.diodes.com/ap2007.pdf.

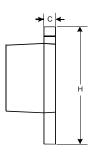
Marking Information



☐ = Manufacturer's code marking K2F = Product Type Marking Code YWW = Date Code Marking Y = Last digit of year ex: 7 = 2007WW = Week code 01 - 52

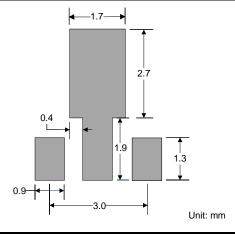
Package Outline Dimensions





SOT89-3L					
Dim	Min	Max	Тур		
Α	1.40	0.160	1.50		
В	0.45	0.55	0.50		
B1	0.37	0.47	0.42		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.50	1.70	1.60		
Е	2.40	2.60	2.50		
е	_	_	1.50		
Н	3.95	4.25	4.10		
L	0.90	1.20	1.05		
All Dimensions in mm					

Suggested Pad Layout



IMPORTANT NOTICE

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